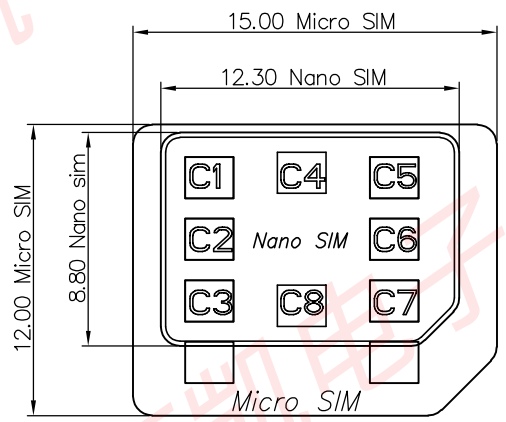
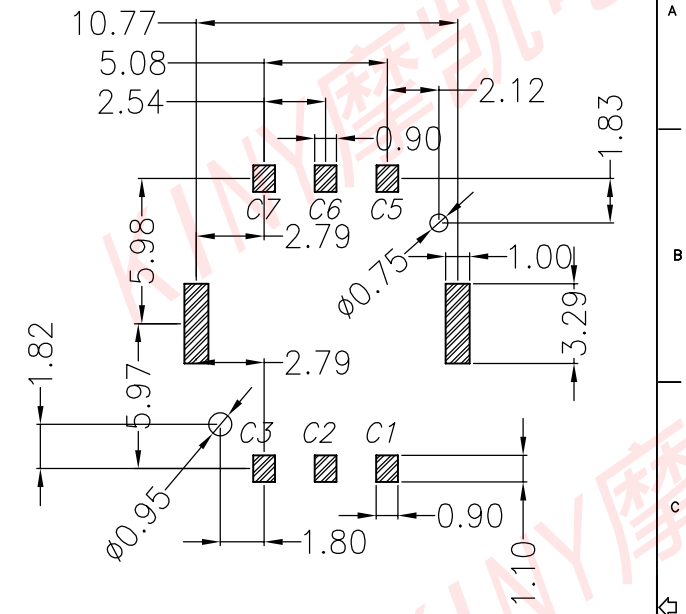
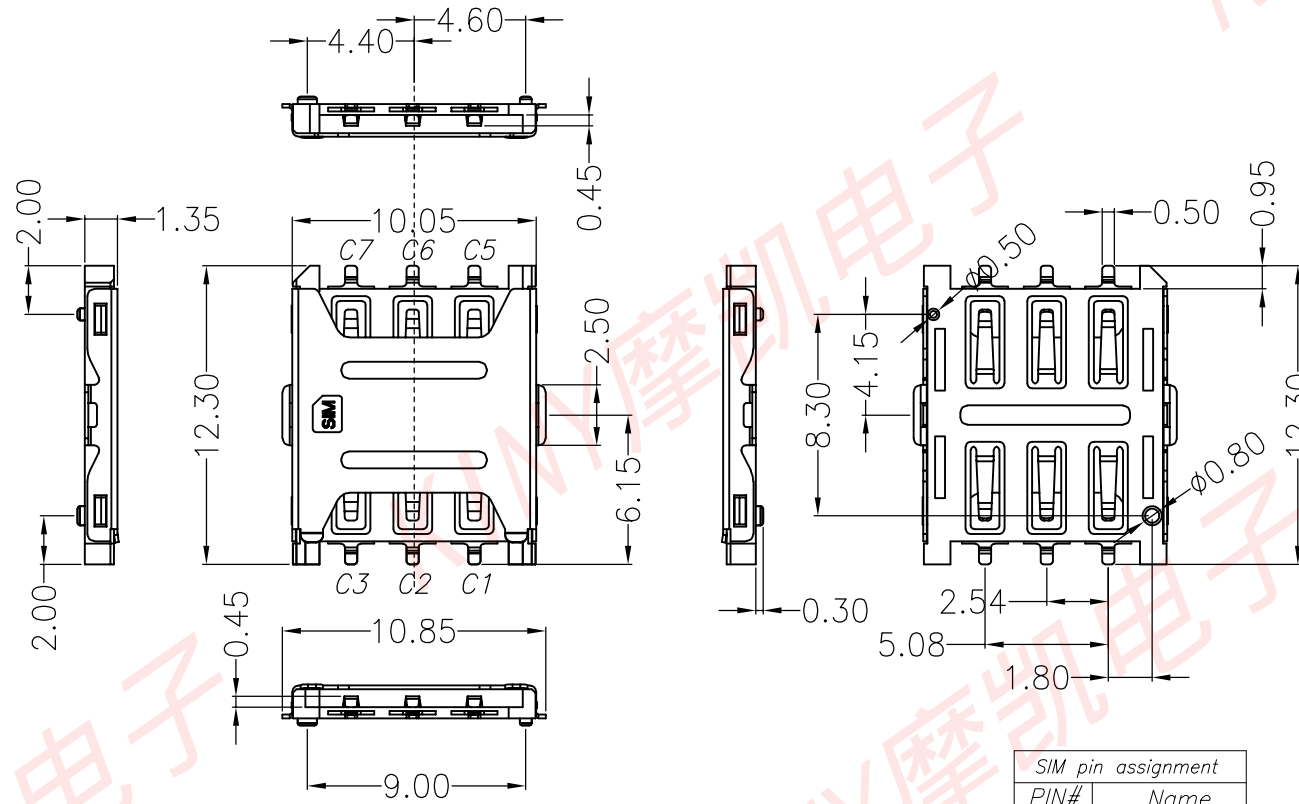


* 所有原料材质, 生产制程, 电镀必须符合H要求



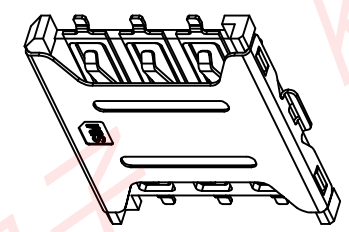
Specification

MATERIAL:
 Insulator: High Temperature Thermoplastic, UL 94V-0.
 Contact: C5210
 SHELL: SUS

PLATING:
 Contact: Plated 50u'' Ni Overall Contact ALL Au 1U,
 Shell: Plated 50u'' Ni Overall, PAD Au 1U

Electrical:
 Current Rating :0.5mA AC/DC max.
 Voltage Rating :125V AC/DC
 Ambient Temperature Range :-20° C~+60° C
 Storage Temperature Range :-40° C~+70° C
 Ambient Humidity Range :95% R.H. Max.
 Contact Resistance:100mΩmax.
 Insulation Resistance:1000MΩmin./500VDC
 Mating Cycles:10,000 Insertions
 Reflow peak temp.: 260° C ±5° C, 3~5 S
 Mating Cycles:3,000 Insertions Min

SIM pin assignment	
PIN#	Name
C1	VCC供电电压
C2	RST重置
C3	CLK时钟
C5	GND接地
C6	VPP程序电压
C7	I/O输入输出



	<h2 style="margin: 0;">东莞市摩凯电子有限公司</h2>				
	DIMENSIONS INIT: mm UNLESS OTHERWISE SPECIFIABLE	PRODUCT NAME : NANO-SIM 卡座NO-PUSH 1.35H 带柱	DRAWING: PING	DATE: 2017.06.06	
	DIMENSION TOLERANCE X.X: ± 0.35 X.XX: ± 0.20 X.XXX: ± 0.10 ANGULAR: ± 2'	PRODUCT NO. : NS135-T1151-10-W	CHECK: Alex	DATE: 2017.06.06	
		DRAWING NO. : D-NS135-T1151-10-W	APPROVED: Alex	DATE: 2017.06.06	
		SCALE: 1:1	DWG ID: C D	REV.: A1	PAGE: 1 OF 1

A	-----	NEW RELEASE	PING	2017.06.06
REVISION NO.	ECR NO.	DESCRIPTION	MARK	DATE
1		2	3	4